

Features

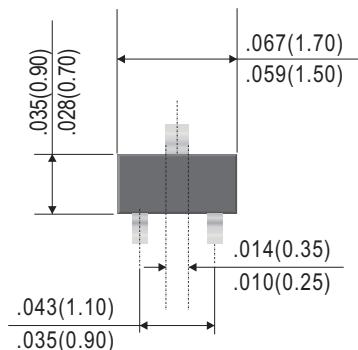
- Pb-Free package is available**

RoHS product for packing code suffix "G"

Halogen free product for packing code suffix "H"

- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

SOT-523



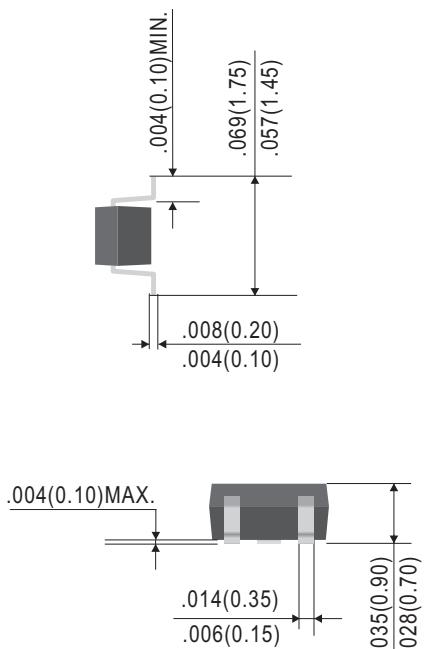
Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit |
|------------------------------|-----------|---------|------|
| Collector-Base Voltage | V_{CBO} | 50 | V |
| Collector-Emitter Voltage | V_{CEO} | 50 | V |
| Emitter-Base voltage | V_{EBO} | 5 | V |
| Collector Current-Continuous | I_C | 100 | mA |
| Collector Dissipation | P_C | 150 | mW |
| Junction Temperature | T_J | 150 | °C |
| Storage Temperature Range | T_{STG} | -55~150 | °C |

Electrical Characteristics

| Sym | Parameter | Min | Typ | Max | Unit |
|---------------|---|-----|-----|-----|------|
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage ($I_L=50\mu A$, $I_E=0$) | 50 | --- | --- | V |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage ($I_L=1mA$, $I_B=0$) | 50 | --- | --- | V |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage ($I_E=50\mu A$, $I_C=0$) | 5 | --- | --- | V |
| I_{CBO} | Collector Cut-off Current ($V_{CB}=50V$, $I_E=0$) | --- | --- | 0.5 | uA |
| I_{EBO} | Emitter Cut-off Current ($V_{EB}=4V$, $I_C=0$) | --- | --- | 0.5 | uA |
| h_{FE} | DC Current Gain ($V_{CE}=5V$, $I_C=1mA$) | 100 | 300 | 600 | --- |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage ($I_C=10mA$, $I_B=1mA$) | --- | --- | 0.3 | V |
| R_1 | Input Resistor | 7 | 10 | 13 | KΩ |
| f_T | Transition Frequency ($V_{CE}=10V$, $I_E=-5mA$, $f=100MHz$) | --- | 250 | --- | MHz |

*Marking: 04



Dimensions in inches and (millimeters)



WILLAS



NPN Digital Transistor

DTC114TE

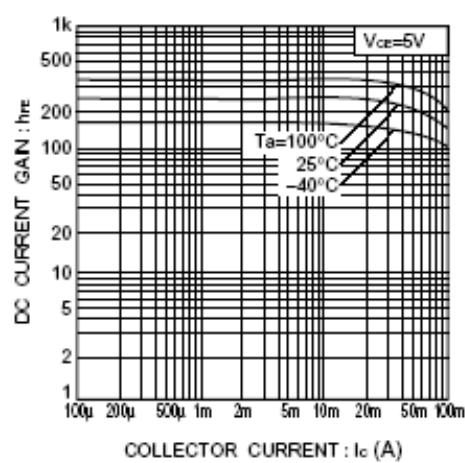


Fig.1 DC current gain vs. collector current

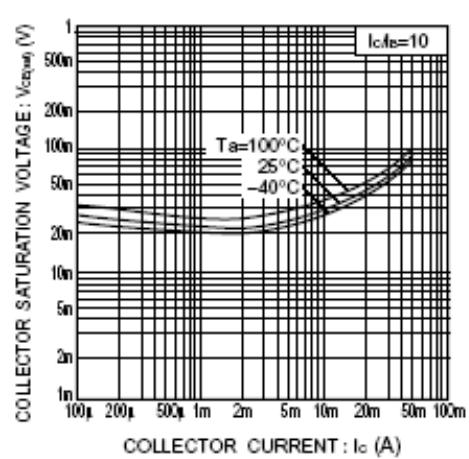


Fig.2 Collector-emitter saturation voltage vs. collector current

● Equivalent circuit

